

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	318	349/153 and (conduct\$ or dummy)and insulat\$ and overlap\$	USPAT	OR	OFF	2003/04/25 10:07
		345/206 and (conduct\$ or dummy)and insulat\$ and overlap\$ and (top adj gate)	USPAT	OR	OFF	2001/07/25 09:00
		349/151 and (conduct\$ or dummy)and insulat\$ and overlap\$ and (top adj gate)	USPAT	OR	OFF	2001/07/25 08:59
		349/149 and (conduct\$ or dummy)and insulat\$ and overlap\$ and (top adj gate)	USPAT	OR	OFF	2001/07/25 08:58
		349/149 and (conduct\$ or dummy)and insulat\$ and overlap\$	USPAT	OR	OFF	2001/07/25 08:57
		349/155 and (conduct\$ or dummy)and insulat\$ and overlap\$	USPAT	OR	OFF	2001/07/25 08:56
		349/190 and (conduct\$ or dummy)and insulat\$ and overlap\$	USPAT	OR	OFF	2001/07/25 08:55
		349/153 and (conduct\$ or dummy)and insulat\$	USPAT	OR	OFF	2001/07/25 08:53
		349/153 and (conduct\$ or dummy)	USPAT	OR	OFF	2001/07/25 08:51
		349/190 and (conduct\$ or dummy)and (top adj gate) and crystal\$	USPAT	OR	OFF	2001/07/25 08:49
		349/153 and (conduct\$ or dummy)and (top adj gate) and crystal\$	USPAT	OR	OFF	2002/05/13 09:43
		349/190	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 13:32
L2	701	349/155	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 13:32
L3	1002	349/149	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 13:32

L4	451	349/151	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 13:32
L5	625	345/206	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 13:33
L6	1164	(liquid adj crystal) and (conduct\$4 or dummy)and (top adj gate) and crystal\$5 and seal\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 13:34
L7	237	(liquid adj crystal) and (conduct\$4 or dummy)and (top adj gate) and crystal\$5 and seal\$4 and semiconductor.as.	USPAT	OR	OFF	2005/09/26 13:34
L8	111	((conduct\$4 or dummy)and (gate or scan\$4)and (data or signal)and seal\$4) near10 insulat\$5 and "349"/\$. ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 13:35
S1	136	349/190	USPAT	OR	OFF	2005/09/26 13:32
S2	321	349/155	USPAT	OR	OFF	2001/07/25 08:40
S3	444	349/149	USPAT	OR	OFF	2001/07/25 08:40
S4	176	349/151	USPAT	OR	OFF	2001/07/25 08:40
S5	309	345/206	USPAT	OR	OFF	2001/07/25 08:42
S6	298	349/153	USPAT	OR	OFF	2001/07/26 08:15
S7	1	"5995189".pn.	USPAT	OR	OFF	2002/02/25 10:05
S8	4	349/153 and (conduct\$ or dummy)and (top adj gate) and crystal\$	USPAT	OR	OFF	2002/05/13 10:06
S9	407	(liquid adj crystal) and (conduct\$ or dummy)and (top adj gate) and crystal\$	USPAT	OR	OFF	2002/05/13 10:16
S10	125	(liquid adj crystal) and (conduct\$ or dummy)and (top adj gate) and crystal\$ and seal\$4	USPAT	OR	OFF	2005/09/26 13:33
S11	33	(liquid adj crystal) and (conduct\$ or dummy)and (top adj gate) and crystal\$ and seal\$4 and semiconductor.as.	USPAT	OR	OFF	2005/09/26 13:34

S12	165	(liquid adj crystal) and (conduct\$ or dummy)and (top adj gate) and crystal\$ and seal\$4 and semiconductor.as.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/25 09:48
S13	96	349/153 and (conduct\$ or dummy)and insulat\$ and overlap\$	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/25 10:16
S14	6	349/153 and 349/141	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/25 10:39
S15	1	JP02214934.ap.	JPO	OR	OFF	2003/11/06 15:09
S16	1	JP04219642.ap.	JPO	OR	OFF	2003/11/06 16:10
S17	755	(liquid adj crystal) and (conduct\$ or dummy)and seal\$4 and semiconductor.as.	US-PGPUB; USPAT; JPO	OR	ON	2003/11/06 17:40
S18	672	(liquid adj crystal) and (conduct\$ or dummy)and seal\$4 and insulat\$5 and semiconductor.as.	US-PGPUB; USPAT; JPO	OR	ON	2003/11/06 17:41
S19	0	(liquid adj crystal) and (conduct\$ or dummy)and seal\$4 and insulat\$5 and semiconductor.as. and "349"/\$.ccls.	USOCR	OR	ON	2003/11/06 17:41
S20	139	(liquid adj crystal) and (conduct\$ or dummy)and seal\$4 and insulat\$5 and semiconductor.as. and "349"/\$.ccls.	US-PGPUB; USPAT; JPO	OR	ON	2003/11/06 17:48
S21	140	(conduct\$ or dummy)and seal\$4 and insulat\$5 and semiconductor.as. and "349"/\$.ccls.	US-PGPUB; USPAT; JPO	OR	ON	2003/11/06 17:49
S22	89	(conduct\$ or dummy)and (gate or scan\$4)and (data or signal)and seal\$4 and insulat\$5 and semiconductor.as. and "349"/\$.ccls.	US-PGPUB; USPAT; JPO	OR	ON	2003/11/06 17:51
S23	5	((conduct\$ or dummy)and (gate or scan\$4)and (data or signal)and seal\$4) near10 insulat\$5 and semiconductor.as. and "349"/\$.ccls.	US-PGPUB; USPAT; JPO	OR	ON	2003/11/06 17:55
S24	79	((conduct\$ or dummy)and (gate or scan\$4)and (data or signal)and seal\$4) near10 insulat\$5 and "349"/\$.ccls.	US-PGPUB; USPAT; JPO	OR	ON	2005/09/26 13:35
S28	5	"5148301".pn. "5179460".pn. "5396356".pn. "5621553".pn. "5745208".pn.	USPAT	OR	OFF	2005/02/16 10:13
S29	1	"5285301".pn.	USPAT	OR	OFF	2005/04/19 08:59